SQR70090ELR

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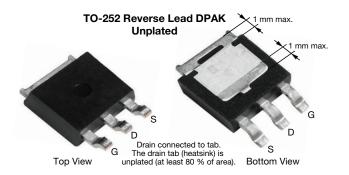
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COMPLIANT HALOGEN

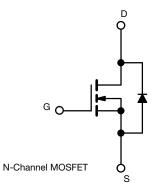
Automotive N-Channel 100 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	100				
$R_{DS(on)}(\Omega)$ at V_{GS} = 10 V	0.0087				
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = 4.5 V	0.0106				
I _D (A)	86				
Configuration	Single				
Package	TO-252 Reverse Lead DPAK				

FEATURES

- TrenchFET® power MOSFET
- Unplated drain tab (heatsink)
- Package with low thermal resistance
- AEC-Q101 qualified
- 100 % $\rm R_g$ and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS	S (T _C = 25 °C, unless	s otherwise noted	(k		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	100	N/	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	I_	86		
	T _C = 125 °C	l _D	50		
Continuous Source Current (Diode conduction) ^a		I _S	100	А	
Pulsed Drain Current ^b		I _{DM}	150		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	45		
Single Pulse Avalanche Energy		E _{AS}	101	mJ	
Mariana Damar Diasia atian b	T _C = 25 °C	D	136	W	
Maximum Power Dissipation ^b	T _C = 125 °C	P _D	45	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB mount ^c	R _{thJA}	50	°C/W	
Junction-to-Case (Drain)		R _{thJC}	1.1		

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		100	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$= 0 \text{ V}, \text{ V}_{\text{GS}} = \pm 20 \text{ V}$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS}=100~V,T_{J}=125~^{\circ}C$	-	-	50	μA	
		$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, \text{ T}_{\text{J}} = 175 ^{\circ}\text{C}$	-	-	250		
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	50	-	-	Α	
		$V_{GS} = 10 V$	I _D = 25 A	-	0.0072	0.0087	Ω	
Drain-Source On-State Resistance ^a	Б	$V_{GS} = 4.5 V$	I _D = 20 A	-	0.0087	0.0106		
Drain-Source On-State Resistance a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 25 A, T _J = 125 °C	-	-	0.0144		
		$V_{GS} = 10 \text{ V}$	I _D = 25 A, T _J = 175 °C	-	-	0.0177		
Forward Transconductance b	9 _{fs}	V _{DS}	V _{DS} = 15 V, I _D = 25 A		80	-	S	
Dynamic ^b		<u>.</u>				•	•	
Input Capacitance	C _{iss}			-	2550	3500	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1350	1900		
Reverse Transfer Capacitance	C _{rss}			-	101	140		
Total Gate Charge ^c	Qg			-	42	65		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 50 \text{ V}, I_D = 50 \text{ A}$	-	7	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	8	-		
Gate Resistance	Rg	f = 1 MHz		1.4	2.9	4.4	Ω	
Turn-On Delay Time ^c	t _{d(on)}				12	20	- ns	
Rise Time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 50 \text{ V}, \ R_{\text{L}} = 1 \ \Omega \\ I_{\text{D}} \cong 50 \text{ A}, \ V_{\text{GEN}} = 10 \text{ V}, \ R_{\text{g}} = 1 \ \Omega \end{array}$		-	5	10		
Turn-Off Delay Time ^c	t _{d(off)}			-	35	60		
Fall Time ^c	t _f			-	6	15		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	150	Α	
Forward Voltage	V _{SD}	I _F =	= 25 A, V _{GS} = 0 V	-	0.88	1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

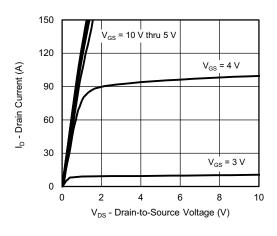
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c. Independent of operating temperature.

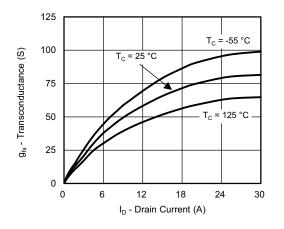
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



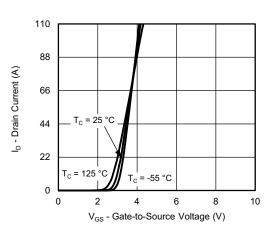
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



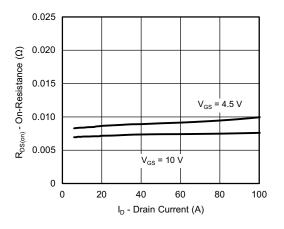
Output Characteristics



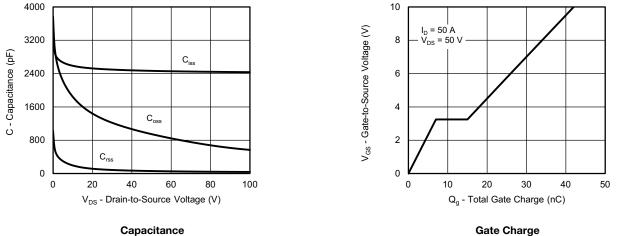
Transconductance



Transfer Characteristics



On-Resistance vs. Drain Current



Capacitance

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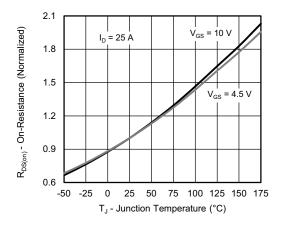
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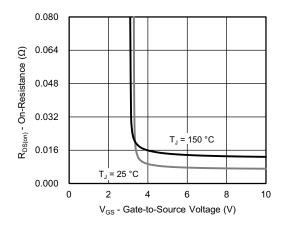
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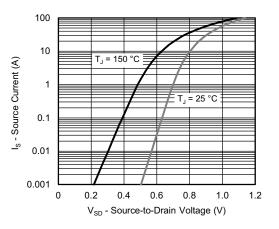
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



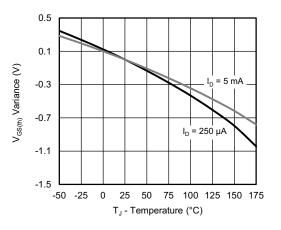
On-Resistance vs. Junction Temperature



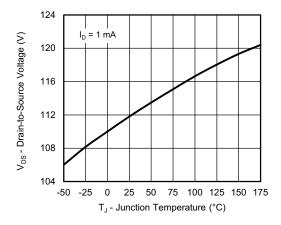
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



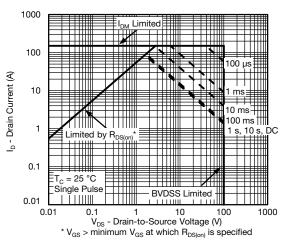
Threshold Voltage



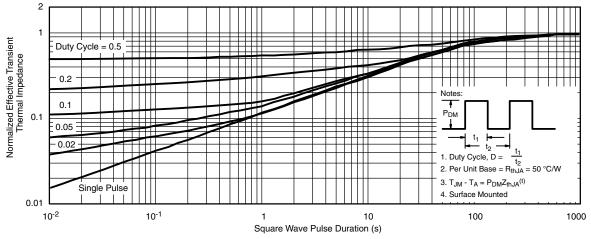
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area



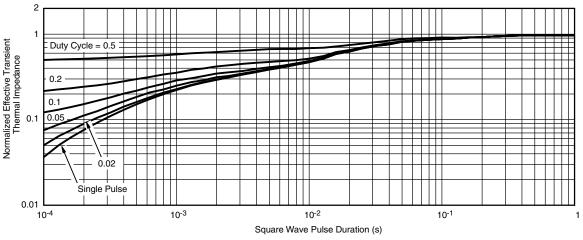
Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

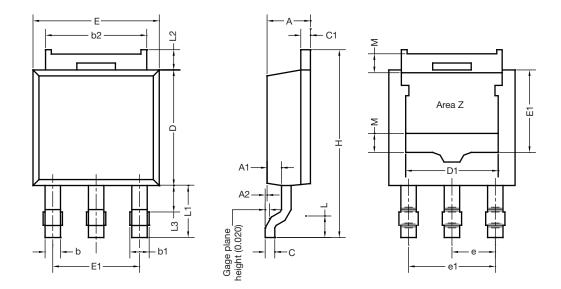
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75462.

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TO-252 Reverse Lead Case Outline



Notes

Dimension L3 for reference only

• Area Z: unplated area more than 80 % heatsink area and for partial plating part only

DIM	MIL	LIMETERS	INCHES			
DIM.	MIN.	MAX.	MIN.	MAX.		
А	2.23	2.33	0.088	0.092		
A1	0.64	0.89	0.025	0.035		
A2	0.03	0.18	0.001	0.007		
b	0.71	0.88	0.028	0.035		
b1	0.76	1.14	0.030	0.045		
b2	5.23	5.44	0.206	0.214		
С	0.46	0.58	0.018	0.023		
C1	0.46	0.58	0.018	0.023		
D	5.97	6.22	0.235	0.245		
D1	4.49	5.00	0.177	0.197		
E	6.48	6.73	0.255	0.265		
E1	4.32	-	0.170	-		
е	2	2.28 BSC		0.090 BSC		
e1	4	4.57 BSC		0.180 BSC		
Н	9.65	10.41	0.380	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74 BSC		C).108 BSC		
L2	0.89	1.27	0.035	0.050		
L3	1.15	1.52	0.040	0.060		
М	-	1.00 (reference only)	-	0.039 (reference only		



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